The ISL85410 is a 1A synchronous buck regulator with an input range of 3 V to 40 V . It provides an easy-to-use, high efficiency low BOM count solution for a variety of applications.

The ISL85410 integrates both high-side and low-side NMOS FETs and features a PFM mode for improved efficiency at light loads. This feature can be disabled if a forced PWM mode is needed. The ISL85410 switches at a default frequency of 500 kHz ; however, it can also be programmed using an external resistor from 300 kHz to 2 MHz . The ISL85410 has the ability to use internal or external compensation. By integrating both NMOS devices and providing internal configuration options, minimal external components are required, which reduces BOM count and complexity of design.

With a wide $\mathrm{V}_{\mathrm{IN}}$ range and reduced BOM, the ISL85410 provides an easy to implement design solution for a variety of applications while giving superior performance. The ISL85410 provides a very robust design for high-voltage industrial applications and an efficient solution for battery powered applications.
The ISL85410 is available in a small Pb-free 4 mmx 3 mm DFN plastic package with a full-range industrial temperature of $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$.

## Related Literature

For a full list of related documents, visit our website:

- ISL85410 device page


## Features

- Wide input voltage range: 3 V to 40 V
- Synchronous operation for high efficiency
- No compensation required
- Integrated high-side and low-side NMOS devices
- Selectable PFM or forced PWM mode at light loads
- Internal fixed frequency $(500 \mathrm{kHz}$ ) or adjustable switching frequency ( 300 kHz to $\mathbf{2 M H z}$ )
- Continuous output current up to 1A
- Internal or external soft-start
- Minimal external components required
- Power-good and enable functions available


## Applications

- Industrial control
- Medical devices
- Portable instrumentation
- Distributed power supplies
- Cloud infrastructure

internal default parameter selection
FIGURE 1. TYPICAL APPLICATION


FIGURE 2. EFFICIENCY vs LOAD, PFM, $\mathrm{V}_{\text {OUT }}=3.3 \mathrm{~V}$

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## Pin Configuration

12 LD 4x3 DFN
TOP VIEW


## Pin Descriptions

| PIN NUMBER | SYMBOL | PIN DESCRIPTION |
| :---: | :---: | :---: |
| 1 | ss | Controls the soft-start ramp time of the output. A single capacitor from the SS pin to ground determines the output ramp rate. See "Soft-Start" on page 14 for soft-start details. If the SS pin is tied to VCC, an internal soft-start of 2 ms is used. |
| 2 | SYNC | Synchronization and light load operational mode selection input. Connect to logic high or VCC for PWM mode. Connect to logic low or ground for PFM mode. Logic ground enables the IC to automatically choose PFM or PWM operation. Connect to an external clock source for synchronization with positive edge trigger. The sync source must be higher than the programmed IC frequency. An internal $5 \mathrm{M} \Omega$ pull-down resistor prevents an undefined logic state if SYNC is left floating. |
| 3 | воот | Floating bootstrap supply pin for the power MOSFET gate driver. The bootstrap capacitor provides the necessary charge to turn on the internal N-Channel MOSFET. Connect an external 100 nF capacitor from this pin to PHASE. |
| 4 | VIN | The input supply for the power stage of the regulator and the source for the internal linear bias regulator. Place a minimum of $4.7 \mu \mathrm{~F}$ ceramic capacitance from VIN to GND and close to the IC for decoupling. |
| 5 | PHASE | Switch node output. It connects the switching FETs with the external output inductor. |
| 6 | PGND | Power ground connection. Connect directly to the system GND plane. |
| 7 | EN | Regulator enable input. The regulator and bias LDO are held off when the pin is pulled to ground. When the voltage on this pin rises above 1V, the chip is enabled. Connect this pin to VIN for automatic start-up. Do not connect the EN pin to VCC because the LDO is controlled by EN voltage. |
| 8 | PG | Open-drain, power-good output that is pulled to ground when the output voltage is below regulation limits or during the soft-start interval. There is an internal $5 \mathrm{M} \Omega$ internal pull-up resistor. |
| 9 | vcc | Output of the internal 5V linear bias regulator. Decouple to PGND with a $1 \mu \mathrm{~F}$ ceramic capacitor at the pin. |
| 10 | FB | Feedback pin for the regulator. FB is the inverting input to the voltage loop error amplifier. COMP is the output of the error amplifier. The output voltage is set by an external resistor divider connected to FB. In addition, the PWM regulator's power-good and UVLO circuits use FB to monitor the regulator output voltage. |
| 11 | COMP | COMP is the output of the error amplifier. When it is tied to VCC, internal compensation is used. When only an RC network is connected from COMP to GND, external compensation is used. See "Loop Compensation Design" on page 17 for more details. |
| 12 | FS | Frequency selection pin. Tie to VCC for 500 kHz switching frequency. Connect a resistor to GND for adjustable frequency from 300 kHz to 2 MHz . |
| EPAD | GND | Signal ground connections. Connect to the application board GND plane with at least five vias. All voltage levels are measured with respect to this pin. The EPAD MUST NOT float. |

## Typical Application Schematics



FIGURE 3. INTERNAL DEFAULT PARAMETER SELECTION


FIGURE 4. USER PROGRAMMABLE PARAMETER SELECTION

TABLE 1. EXTERNAL COMPONENT SELECTION

| $\mathrm{V}_{\text {OUT }}(\mathrm{V})$ | $\mathrm{L}_{1}(\mu \mathrm{H})$ | $\mathrm{C}_{\text {OUT }}(\mu \mathrm{F})$ | $\mathrm{R}_{2}(\mathrm{k} \Omega)$ | $\mathrm{R}_{3}(\mathrm{k} \Omega)$ | $\mathrm{C}_{\mathrm{FB}}(\mathrm{pF})$ | $\mathrm{R}_{\mathrm{FS}}(\mathrm{k} \Omega$ ) | $\mathbf{R}_{\text {COMP }}(\mathrm{k} \Omega$ ) | $\mathrm{C}_{\text {COMP }}(\mathrm{pF})$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 12 | 22 | $2 \times 22$ | 90.9 | 4.75 | 22 | 115 | 150 | 470 |
| 5 | 22 | $47+22$ | 90.9 | 12.4 | 27 | DNP (Note 1) | 100 | 470 |
| 3.3 | 22 | $47+22$ | 90.9 | 20 | 27 | DNP ( Note 1) | 100 | 470 |
| 2.5 | 22 | $47+22$ | 90.9 | 28.7 | 27 | DNP (Note 1) | 100 | 470 |
| 1.8 | 12 | $47+22$ | 90.9 | 45.5 | 27 | DNP ( Note 1) | 70 | 470 |

NOTE:

1. Connect FS to $\mathrm{V}_{\mathrm{Cc}}$.

## Functional Block Diagram



## Ordering Information

| PART NUMBER <br> (Notes 3, 4) | PART <br> MARKING | TEMP. RANGE <br> $\left({ }^{\circ} \mathrm{C}\right)$ | TAPE AND REEL <br> (Units) (Note 2) | PACKAGE <br> (RoHS Compliant) | PKG. <br> DWG. \# |
| :--- | :--- | :---: | :---: | :---: | :---: |
| ISL85410FRZ | 5410 | -40 to +125 | - | 12 Ld DFN | L12.4x3 |
| ISL85410FRZ-T | 5410 | -40 to +125 | 6 k | 12 Ld DFN | L12.4x3 |
| ISL85410FRZ -T7A | 5410 | -40 to +125 | 250 | 12 Ld DFN | L12.4x3 |
| ISL85410EVAL1Z | Evaluation Board |  |  |  |  |
| ISL85410DEM01Z |  |  |  |  |  |

NOTES:
2. See TB347 for details about reel specifications.
3. These Pb -free plastic packaged products employ special Pb -free material sets, molding compounds/die attach materials, and $100 \%$ matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb -free soldering operations). Pb -free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
4. For Moisture Sensitivity Level (MSL), see the ISL85410 device page. For more information about MSL, see TB363.


## Thermal Information

| Thermal Resistance | $\theta_{\mathrm{JA}}\left({ }^{\circ} \mathrm{C} / \mathrm{W}\right)$ | $\theta_{\mathrm{JC}}\left({ }^{\circ} \mathrm{C} / \mathrm{W}\right)$ |
| :---: | :---: | :---: |
| DFN Package (Notes 5, 6) | 42 | 4.5 |
| Maximum Junction Temperature (Plastic | kage) | . $+150^{\circ} \mathrm{C}$ |
| Maximum Storage Temperature Range |  | $5^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Ambient Temperature Range |  | $0^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Operating Junction Temperature Range |  | $0^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Pb-Free Reflow Profile |  | see TB493 |

## Recommended Operating Conditions

Temperature
. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ Supply Voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . +3 C to +40 V

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions can adversely impact product reliability and result in failures not covered by warranty.

NOTES:
5. $\theta_{\mathrm{JA}}$ is measured in free air with the component mounted on a high-effective thermal conductivity test board with "direct attach" features. See TB379 for details.
6. For $\theta_{\mathrm{JC}}$, the "case temp" location is the center of the exposed metal pad on the package underside.

Electrical Specifications $T_{A}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}, \mathrm{V}_{I N}=3 \mathrm{~V}$ to 40 V , unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$. Boldface limits apply across the junction temperature range, $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN (Note 9) | TYP | MAX (Note 9) | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SUPPLY VOLTAGE |  |  |  |  |  |  |
| $\mathrm{V}_{\text {IN }}$ Voltage Range | $\mathrm{V}_{\mathrm{IN}}$ |  | 3 |  | 40 | V |
| $\mathrm{V}_{\text {IN }}$ Quiescent Supply Current | $\mathrm{I}_{\mathrm{Q}}$ | $\mathrm{V}_{\mathrm{FB}}=0.7 \mathrm{~V}, \mathrm{SYNC}=0 \mathrm{~V}, \mathrm{f}_{\mathrm{SW}}=\mathrm{V}_{\mathrm{CC}}$ |  | 80 |  | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {IN }}$ Shutdown Supply Current | $I_{\text {SD }}$ | $\mathrm{EN}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=40 \mathrm{~V}(\underline{\text { Note 7 }}$ ) |  | 2 | 4 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {CC }}$ Voltage | $\mathrm{V}_{\mathrm{CC}}$ | $\mathrm{V}_{\text {IN }}=6 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=0$ to 10 mA | 4.5 | 5.1 | 5.7 | V |
| POWER-ON RESET |  |  |  |  |  |  |
| $\mathrm{V}_{\text {CC }}$ POR Threshold |  | Rising edge |  | 2.75 | 2.95 | V |
|  |  | Falling edge | 2.35 | 2.6 |  | V |
| OSCILLATOR |  |  |  |  |  |  |
| Nominal Switching Frequency | fsw | FS pin $=\mathrm{V}_{\text {CC }}$ | 430 | 500 | 570 | kHz |
|  |  | Resistor from the FS pin to GND $=340 \mathrm{k} \Omega$ | 240 | 300 | 360 | kHz |
|  |  | Resistor from the FS pin to GND $=32.4 \mathrm{k} \Omega$ |  | 2000 |  | kHz |
| Minimum Off-Time | $\mathrm{t}_{\text {MIN_OFF }}$ | $\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ |  | 150 |  | ns |
| Minimum On-Time | $\mathrm{t}_{\text {MIN_ON }}$ | (Note 10) |  | 90 |  | ns |
| FS Voltage | $\mathrm{V}_{\mathrm{FS}}$ | $\mathrm{R}_{\mathrm{FS}}=100 \mathrm{k} \Omega$ | 0.39 | 0.4 | 0.41 | V |
| Synchronization Frequency | SYNC |  | 300 |  | 2000 | kHz |
| SYNC Pulse Width |  |  | 100 |  |  | ns |
| ERROR AMPLIFIER |  |  |  |  |  |  |
| Error Amplifier Transconductance Gain | $g_{m}$ | External compensation | 165 | 230 | 295 | $\mu \mathrm{A} / \mathrm{V}$ |
|  |  | Internal compensation |  | 50 |  | $\mu \mathrm{A} / \mathrm{V}$ |
| FB Leakage Current |  | $\mathrm{V}_{\mathrm{FB}}=0.6 \mathrm{~V}$ |  | 1 | 150 | nA |
| Current Sense Amplifier Gain | $\mathrm{R}_{\mathrm{T}}$ |  | 0.46 | 0.5 | 0.54 | V/A |
| FB Voltage |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 0.590 | 0.599 | 0.606 | V |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 0.590 | 0.599 | 0.607 | V |

Electrical Specifications $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}, \mathrm{V}_{I N}=3 \mathrm{~V}$ to 40 V , unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$. Boldface limits apply across the junction temperature range, $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ (Continued)

| PARAMETER | SYMBOL | TEST CONDITIONS | $\begin{gathered} \text { MIN } \\ \text { (Note } 9 \text { ) } \end{gathered}$ | TYP | $\begin{gathered} \text { MAX } \\ \text { (Note } 9 \text { ) } \end{gathered}$ | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| POWER-GOOD |  |  |  |  |  |  |
| Lower PG Threshold - VFB Rising |  |  |  | 90 | 94 | \% |
| Lower PG Threshold - VFB Falling |  |  | 82.5 | 86 |  | \% |
| Upper PG Threshold - VFB Rising |  |  |  | 116.5 | 120 | \% |
| Upper PG Threshold - VFB Falling |  |  | 107 | 112 |  | \% |
| PG Propagation Delay |  | Percentage of the soft-start time |  | 10 |  | \% |
| PG Low Voltage |  | $\mathrm{I}_{\text {SINK }}=3 \mathrm{~mA}, \mathrm{EN}=\mathrm{V}_{\mathrm{CC}}, \mathrm{V}_{\mathrm{FB}}=0 \mathrm{~V}$ |  | 0.05 | 0.3 | v |
| TRACKING AND SOFT-START |  |  |  |  |  |  |
| Soft-Start Charging Current | Iss |  | 4.2 | 5.5 | 6.5 | $\mu \mathrm{A}$ |
| Internal Soft-Start Ramp Time |  | $\mathrm{EN} / \mathrm{SS}=\mathrm{V}_{\text {CC }}$ | 1.5 | 2.4 | 3.4 | ms |
| FAULT PROTECTION |  |  |  |  |  |  |
| Thermal Shutdown Temperature | $\mathrm{T}_{\text {SD }}$ | Rising threshold |  | 150 |  | ${ }^{\circ} \mathrm{C}$ |
|  | $\mathrm{T}_{\mathrm{HYS}}$ | Hysteresis |  | 20 |  | ${ }^{\circ} \mathrm{C}$ |
| Current Limit Blanking Time | $\mathrm{t}_{\text {OCON }}$ |  |  | 17 |  | Clock pulses |
| Overcurrent and Auto Restart Period | tocoff |  |  | 8 |  | SS cycle |
| Positive Peak Current Limit | IPLIMIT | (Note 8) | 1.3 | 1.5 | 1.7 | A |
| PFM Peak Current Limit | IPK_PFM |  | 0.34 | 0.4 | 0.5 | A |
| Zero Cross Threshold |  |  |  | 15 |  | mA |
| Negative Current Limit | INLIMIT | (Note 8) | -0.67 | -0.6 | -0.53 | A |
| POWER MOSFET |  |  |  |  |  |  |
| High-Side | $\mathrm{R}_{\mathrm{HDS}}$ | $\mathrm{I}_{\text {PHASE }}=100 \mathrm{~mA}, \mathrm{~V}_{\text {cC }}=5 \mathrm{~V}$ |  | 250 | 350 | $\mathrm{m} \Omega$ |
| Low-Side | RLDS | $\mathrm{I}_{\text {PHASE }}=100 \mathrm{~mA}, \mathrm{~V}_{\text {CC }}=5 \mathrm{~V}$ |  | 90 | 130 | $\mathrm{m} \Omega$ |
| PHASE Leakage Current |  | $\mathrm{EN}=$ PHASE $=0 \mathrm{~V}$ |  |  | 300 | nA |
| PHASE Rise Time | $\mathrm{t}_{\text {RISE }}$ | $\mathrm{V}_{\mathrm{IN}}=40 \mathrm{~V}$ |  | 10 |  | ns |
| EN/SYNC |  |  |  |  |  |  |
| Input Threshold |  | Falling edge, logic low | 0.4 | 1 |  | v |
|  |  | Rising edge, logic high |  | 1.2 | 1.4 | V |
| EN Logic Input Leakage Current |  | EN $=0 \mathrm{~V} / 40 \mathrm{~V}$ | -0.5 |  | 0.5 | $\mu \mathrm{A}$ |
| SYNC Logic Input Leakage Current |  | SYNC $=0 \mathrm{~V}$ |  | 10 | 100 | nA |
|  |  | SYNC $=5 \mathrm{~V}$ |  | 1.0 | 1.55 | $\mu \mathrm{A}$ |

## NOTES:

7. Test condition: $\mathrm{V}_{\mathrm{IN}}=40 \mathrm{~V}, \mathrm{FB}$ forced above regulation point $(0.6 \mathrm{~V})$, switching and power MOSFET gate charging current not included.
8. Established by both current sense amplifier gain test and current sense amplifier output test at $\mathrm{I}_{\mathrm{L}}=0 \mathrm{~A}$.
9. Parameters with MIN and/or MAX limits are $100 \%$ tested at $+25^{\circ} \mathrm{C}$, unless otherwise specified. Temperature limits established by characterization and are not production tested.
10. Minimum on-time required to maintain loop stability.

Efficiency Curves $\mathrm{f}_{\mathrm{sw}}=500 \mathrm{kHz}, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$


FIGURE 5. EFFICIENCY vs LOAD, PFM, $\mathrm{V}_{\text {OUT }}=12 \mathrm{~V}$


FIGURE 7. EFFICIENCY vs LOAD, PFM, $\mathrm{V}_{\mathbf{O U T}}=5 \mathrm{~V}, \mathrm{~L}_{\mathbf{1}}=\mathbf{3 0} \mu \mathrm{H}$


FIGURE 9. EFFICIENCY vs LOAD, PFM, $\mathrm{V}_{\text {OUT }}=3.3 \mathrm{~V}$


FIGURE 6. EFFICIENCY vs LOAD, PWM, $\mathrm{V}_{\text {OUT }}=12 \mathrm{~V}$


FIGURE 8. EFFICIENCY vs LOAD, PWM, $V_{O U T}=5 V, L_{1}=30 \mu H$


FIGURE 10. EFFICIENCY vs LOAD, PWM, $\mathrm{V}_{\text {OUT }}=3.3 \mathrm{~V}$

## Efficiency Curves $\mathrm{f}_{\mathrm{SW}}=500 \mathrm{kHz}, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (Continued)



FIGURE 11. EFFICIENCY vs LOAD, PFM, $\mathrm{V}_{\text {OUT }}=1.8 \mathrm{~V}$


FIGURE 13. $\mathrm{V}_{\text {OUT }}$ REGULATION vs LOAD, PWM, $\mathrm{V}_{\text {OUT }}=5 \mathrm{~V}, \mathrm{~L}_{\mathbf{1}}=\mathbf{3 0} \mu \mathrm{H}$


FIGURE 15. $V_{\text {OUT }}$ REGULATION vs LOAD, PWM, $\mathrm{V}_{\text {OUT }}=3.3 \mathrm{~V}$


FIGURE 12. EFFICIENCY vs LOAD, PWM, $\mathrm{V}_{\text {OUT }}=\mathbf{1 . 8 \mathrm { V }}$


FIGURE 14. $V_{\text {OUT }}$ REGULATION vs LOAD, PFM, $\mathrm{V}_{\text {OUT }}=5 \mathrm{~V}, \mathrm{~L}_{1}=\mathbf{3 0 \mu H}$


FIGURE 16. $\mathrm{V}_{\text {OUT }}$ REGULATION vs LOAD, PFM, $\mathrm{V}_{\text {OUT }}=3.3 \mathrm{~V}$

Efficiency Curves $\mathrm{f}_{\mathrm{SW}}=500 \mathrm{kHz}, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (Continued)


FIGURE 17. $\mathrm{V}_{\text {OUT }}$ REGULATION vs LOAD, PWM, $\mathrm{V}_{\text {OUT }}=1.8 \mathrm{~V}$


FIGURE 18. $\mathrm{V}_{\text {OUT }}$ REGULATION vs LOAD, PFM, $\mathrm{V}_{\text {OUT }}=1.8 \mathrm{~V}$

Measurements ${ }_{\mathrm{tsw}}=50 \mathrm{oktz}, \mathrm{v}_{\mathrm{N}}=24 \mathrm{~V}, \mathrm{~V}_{\mathrm{our}}=3.3,3, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$


FIGURE 19. START-UP AT NO LOAD, PFM


FIGURE 21. SHUTDOWN AT NO LOAD, PFM


FIGURE 20. START-UP AT NO LOAD, PWM


FIGURE 22. SHUTDOWN AT NO LOAD, PWM

Measurements $\mathrm{f}_{\mathrm{SW}}=500 \mathrm{kHz}, \mathrm{v}_{\mathrm{IN}}=24 \mathrm{~V}, \mathrm{v}_{\mathrm{OUT}}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (Continued)


FIGURE 23. START-UP AT 1A, PWM


FIGURE 25. START-UP AT 1A, PFM


FIGURE 27. JITTER AT NO LOAD, PWM


FIGURE 24. SHUTDOWN AT 1A, PWM


FIGURE 28. JITTER AT 1A LOAD, PWM

Measurements $f_{S W}=500 \mathrm{kHz}, \mathrm{v}_{\text {IN }}=24 \mathrm{~V}, \mathrm{v}_{\text {OUT }}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (Continued)


FIGURE 29. STEADY STATE AT NO LOAD, PFM


FIGURE 31. STEADY STATE AT 1A, PWM


FIGURE 33. LIGHT LOAD OPERATION AT 20mA, PWM


Measurements $f_{\text {Sw }}=500 \mathrm{kHz}, \mathrm{V}_{1 \mathbb{}}=24 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (Continued)



FIGURE 36. PFM TO PWM TRANSITION


FIGURE 38. OVERCURRENT PROTECTION HICCUP, PWM



FIGURE 39. SYNC AT 1A LOAD, PWM

Measurements
$\mathrm{f}_{\mathrm{SW}}=500 \mathrm{kHz}, \mathrm{V}_{\mathrm{IN}}=24 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (Continued)


FIGURE 41. NEGATIVE CURRENT LIMIT RECOVERY, PWM

## Detailed Description

The ISL85410 combines a synchronous buck PWM controller with integrated power switches. The buck controller drives internal high-side and low-side N-channel MOSFETs to deliver load current up to 1A. The buck regulator can operate from an unregulated DC source, such as a battery, with a voltage ranging from +3 V to +40 V . An internal LDO provides bias to the low voltage portions of the IC.

Peak current mode control is used to simplify feedback loop compensation and reject input voltage variation. User selectable internal feedback loop compensation further simplifies design. The ISL85410 switches at a default 500kHz.

The buck regulator is equipped with an internal current sensing circuit and the peak current limit threshold is typically set at 1.5A.

## Power-On Reset

The ISL85410 automatically initializes upon receipt of the input power supply and continually monitors the EN pin state. If EN is held below its logic rising threshold, the IC is held in shutdown and consumes typically $2 \mu \mathrm{~A}$ from the $\mathrm{V}_{\mathrm{IN}}$ supply. If EN exceeds its logic rising threshold, the regulator enables the bias LDO and begins to monitor the VCC pin voltage. When the VCC pin voltage clears its rising POR threshold, the controller initializes the switching regulator circuits. If VCC never clears the rising POR threshold, the controller does not allow the switching regulator to operate. If VCC falls below its falling POR threshold while the switching regulator is operating, the switching regulator is shut down until VCC returns.

## Soft-Start

To avoid large in-rush current, $\mathrm{V}_{\mathrm{OUT}}$ is slowly increased at start-up to its final regulated value. Soft-start time is determined by the SS pin connection. If SS is pulled to VCC, an internal 2 ms timer is selected for soft-start. For other soft-start times, connect a capacitor from SS to GND. In this case, a $5.5 \mu \mathrm{~A}$ current pulls up the SS voltage and the FB pin follows this ramp until it reaches the 600 mV reference level. The soft-start time for this case is described by Equation 1:

Time(ms) $=\mathrm{C}(\mathrm{nF}) * 0.109$


FIGURE 42. OVER-TEMPERATURE PROTECTION, PWM

## Power-Good

PG is the open-drain output of a window comparator that continuously monitors the buck regulator output voltage vrom the FB pin. PG is actively held low when EN is low and during the buck regulator soft-start period. After the soft-start period completes, PG becomes high impedance if the FB pin is within the range specified in the "Electrical Specifications" on page 7. If FB exits the specified window, PG is pulled low until FB returns. Over-temperature faults also force PG low until the fault condition is cleared by an attempt to soft-start. There is an internal $5 \mathrm{M} \Omega$ internal pull-up resistor.

## PWM Control Scheme

The ISL85410 employs peak current-mode pulse-width modulation (PWM) control for fast transient response and pulse-by-pulse current limiting, as shown in the "Functional Block Diagram" on page 5. The current loop consists of the current sensing circuit, slope compensation ramp, PWM comparator, oscillator, and latch. Current sense trans-resistance is typically $500 \mathrm{mV} / \mathrm{A}$ and slope compensation rate, Se , is typically $450 \mathrm{mV} / \mathrm{T}$ where $T$ is the switching cycle period. The control reference for the current loop comes from the error amplifier's output (VCOMP).
A PWM cycle begins when a clock pulse sets the PWM latch and the upper FET is turned on. Current begins to ramp up in the upper FET and inductor. This current is sensed ( $\mathrm{V}_{\mathrm{CSA}}$ ), converted to a voltage and summed with the slope compensation signal. This combined signal is compared to $\mathrm{V}_{\text {COMP }}$ and when the signal is equal to $\mathrm{V}_{\text {COMP }}$, the latch is reset. Upon latch reset, the upper FET is turned off and the lower FET turned on allowing current to ramp down in the inductor. The lower FET remains on until the clock initiates another PWM cycle. Figure 44 shows the typical operating waveforms during the PWM operation. The dotted lines illustrate the sum of the current sense and slope compensation signal.
Output voltage is regulated as the error amplifier varies VCOMP and therefore varies the output inductor current. The error amplifier is a transconductance type and its output (COMP) is terminated with a series RC network to GND. This termination is internal ( $150 \mathrm{k} / 54 \mathrm{pF}$ ) if the COMP pin is tied to VCC. Additionally, the transconductance for COMP = VCC is $50 \mu \mathrm{~A} / \mathrm{V}$ vs $230 \mu \mathrm{~A} / \mathrm{V}$ for external RC connection. Its noninverting input is internally connected to a 600 mV reference voltage and its inverting input is connected to the output voltage from the FB pin and its associated divider network.


FIGURE 43. DCM MODE OPERATION WAVEFORMS


FIGURE 44. PWM OPERATION WAVEFORMS

## Light Load Operation

At light loads, converter efficiency can be improved by enabling variable frequency operation (PFM). Connecting the SYNC pin to GND allows the controller to choose such operation automatically when the load current is low. Figure 43 shows the DCM operation. The IC enters DCM mode when eight consecutive cycles of inductor current crossing zero are detected. This corresponds to a load current equal to $1 / 2$ the peak-to-peak inductor ripple current and set by Equation 2 :
$\mathrm{I}_{\text {OUT }}=\frac{\mathrm{V}_{\text {OUT }}(1-\mathrm{D})}{2 \mathrm{f}_{\mathrm{SW}}}$
where $\mathrm{D}=$ duty cycle, $\mathrm{f}_{\mathrm{SW}}=$ switching frequency, $\mathrm{L}=$ inductor value, $\mathrm{I}_{\text {OUT }}=$ output loading current, $\mathrm{V}_{\text {OUT }}=$ output voltage.
While operating in PFM mode, the regulator controls the output voltage with a simple comparator and pulsed FET current. A comparator indicates the point at which FB is equal to the 600 mV reference, at which time the regulator begins providing pulses of current until FB is moved above the 600 mV reference by $1 \%$. The current pulses are approximately 400 mA and are issued at a frequency equal to the converter's programmed PWM operating frequency.
Due to the pulsed current nature of PFM mode, the converter can supply limited current to the load. If load current rises beyond the
limit, $\mathrm{V}_{\text {OUT }}$ begins to decline. A second comparator signals an FB voltage $2 \%$ lower than the 600 mV reference and forces the converter to return to PWM operation.

## Output Voltage Selection

The regulator output voltage is programmed using an external resistor divider to scale $\mathrm{V}_{\text {OUT }}$ relative to the internal reference voltage. The scaled voltage is applied to the inverting input of the error amplifier; see Figure 45.
The output voltage programming resistor, $\mathbf{R}_{\mathbf{3}}$, depends on the value chosen for the feedback resistor, $\mathrm{R}_{2}$, and the needed output voltage, $\mathrm{V}_{\text {OUT }}$, of the regulator. Equation 3 describes the relationship between $\mathrm{V}_{\text {OUT }}$ and resistor values.
$R_{3}=\frac{R_{2} \times 0.6 \mathrm{~V}}{\mathrm{~V}_{\text {OUT }}-0.6 \mathrm{~V}}$
If the needed output voltage is 0.6 V , then $\mathrm{R}_{\mathbf{3}}$ is left unpopulated and $R_{2}$ is $0 \Omega$.


FIGURE 45. EXTERNAL RESISTOR DIVIDER

## Protection Features

The ISL85410 is protected from overcurrent, negative overcurrent and over-temperature. The protection circuits operate automatically.

## Overcurrent Protection

During PWM on-time, current through the upper FET is monitored and compared to a nominal 1.5A peak overcurrent limit. If current reaches the limit, the upper FET is turned off until the
next switching cycle. In this way, FET peak current is always well limited.

If the overcurrent condition persists for 17 sequential clock cycles, the regulator begins its hiccup sequence. In this case, both FETs are turned off and PG is pulled low. This condition is maintained for eight soft-start periods, after which the regulator attempts a normal soft-start.

If output fault persists, the regulator repeats the hiccup sequence indefinitely. There is no danger even if the output is shorted during soft-start.

If $\mathrm{V}_{\text {OUT }}$ is shorted very quickly, FB may collapse below $5 / 8^{\text {ths }}$ of its target value before 17 cycles of overcurrent are detected. The ISL85410 recognizes this condition and begins to lower its switching frequency proportional to the FB pin voltage. This adjustment ensures that the inductor current does not run away under any circumstance (even with VOUT near OV).

## Negative Current Limit

If an external source somehow drives current into $\mathrm{V}_{\text {OUT }}$, the controller attempts to regulate $\mathrm{V}_{\text {OUT }}$ by reversing its inductor current to absorb the externally sourced current. If the external source is low impedance, the current may be reversed to unacceptable levels and the controller initiates its negative current limit protection. Similar to normal overcurrent, the negative current protection is realized by monitoring the current through the lower FET. When the valley point of the inductor current reaches negative current limit, the lower FET is turned off and the upper FET is forced on until current reaches the POSITIVE current limit or an internal clock signal is issued. Next, the lower FET is allowed to operate. If the current is pulled to the negative limit again on the next cycle, the upper FET is forced on again and the current is forced to $1 / 6^{\text {th }}$ of the positive current limit. Next, the controller turns off both FETs and waits for COMP to indicate a return to normal operation. During this time, the controller applies a $100 \Omega$ load from PHASE to PGND and attempts to discharge the output. Negative current limit is a pulse-by-pulse style operation and recovery is automatic.

## Over-Temperature Protection

Over-temperature protection limits maximum junction temperature in the ISL85410. When junction temperature ( $\mathrm{T}_{\mathrm{J}}$ ) exceeds $+150^{\circ} \mathrm{C}$, both FETs are turned off and the controller waits for temperature to decrease by approximately $20^{\circ} \mathrm{C}$. During this time PG is pulled low. When temperature is within an acceptable range, the controller initiates a normal soft-start sequence. For continuous operation, do not exceed the $+125^{\circ} \mathrm{C}$ junction temperature rating.

## Boot UndervoItage Protection

If the boot capacitor voltage falls below 1.8 V , the boot undervoltage protection circuit turns on the lower FET for 400 ns to recharge the capacitor. This operation may arise during long periods of no switching such as PFM no load situations. In PWM operation near dropout ( $\mathrm{V}_{I N}$ near $\mathrm{V}_{\text {OUT }}$ ), the regulator can hold the upper FET on for multiple clock cycles. To prevent the boot capacitor from discharging, the lower FET is forced on for approximately 200 ns every 10 clock cycles.

## Application Guidelines

## Simplifying the Design

While the ISL85410 offers user programmed options for most parameters, the easiest implementation with fewest components involves selecting internal settings for SS, COMP, and FS. Table 1 on page 4 provides component value selections for a variety of output voltages and allows you to implement solutions with a minimum of effort.

## Operating Frequency

The ISL85410 operates at a default switching frequency of 500 kHz if the FS pin is tied to $\mathrm{V}_{\mathrm{CC}}$. Tie a resistor from the FS pin to GND to program the switching frequency from 300 kHz to 2 MHz , as shown in Equation 4.
$\mathrm{R}_{\mathrm{FS}}[\mathrm{k} \Omega]=108.75 \mathrm{k} \Omega *(\mathrm{t}-0.2 \mu \mathrm{~s}) / 1 \mu \mathrm{~s}$
Where:
$t$ is the switching period in $\mu \mathrm{s}$.


FIGURE 46. RFS SELECTION vs fsw

## Minimum On/Off-Time Limitation

Minimum on-time ( $\mathrm{t}_{\mathrm{MIN} \text { _ON }}$ ) is the shortest duration of time that the HS FET can be turned on and minimum off time ( $\mathrm{t}_{\text {MIN_OFF }}$ ) is the shortest duration of time that the HS FET can be turned off. The typical $\mathrm{t}_{\text {MIN_ON }}$ is 90 ns and the typical $\mathrm{t}_{\text {MIN_OFF }}$ is 150 ns . For a given $\mathrm{t}_{\text {MIN_ON }}$ and $\mathrm{t}_{\text {MIN_OFF }}$, a higher switching frequency results in a narrower range of allowed duty cycle, which translates to a smaller allowed $V_{I N}$ range.

For a given output voltage ( $\mathrm{V}_{\mathrm{OUT}}$ ) and switching frequency ( $\mathrm{f}_{\mathrm{SW}}$ ), the maximum allowed voltage is given by (Equation 5):
$V_{\text {IN(max) }}=\frac{V_{\text {OUT }}}{f_{\text {SW }} \times \mathrm{t}_{\text {MIN_ON }}}$
The minimum allowed voltage is given by (Equation 6):
$V_{\text {IN }(\text { min })}=\frac{V_{\text {OUT }}}{1-\mathrm{f}_{\text {SW }} \times \mathrm{t}_{\text {MIN_OFF }}}$

Table 2 shows the recommended switching frequencies for the various $\mathrm{V}_{\text {OUT }}$ to operate up to the maximum $\mathrm{V}_{\mathrm{IN}}(40 \mathrm{~V})$.

TABLE 2. RECOMMENDED SWITCHING FREQUENCIES FOR VARIOUS $V_{\text {OUT }}$

| $\mathbf{V}_{\mathbf{I N}(\max )}(\mathrm{V})$ | $\mathbf{V}_{\mathbf{O U T}}(\mathrm{V})$ | $\mathbf{f}_{\mathbf{S W}}(\mathbf{k H z})$ |
| :---: | :---: | :---: |
| 40 | 5 | 500 |
| 40 | 3.3 | 500 |
| 40 | 2.5 | 500 |
| 40 | 1.8 | 300 |

## Synchronization Control

The frequency of operation can be synchronized up to 2 MHz by an external signal applied to the SYNC pin. The rising edge on the SYNC triggers the rising edge of PHASE. To properly sync, the external source must be at least $10 \%$ greater than the programmed free running IC frequency.

## Output Inductor Selection

The inductor value determines the converter's ripple current. Choosing an inductor current requires a somewhat arbitrary choice of ripple current, $\Delta \mathrm{I}$. A reasonable starting point is $30 \%$ of total load current. The inductor value can then be calculated using Equation 7:
$L=\frac{V_{\text {IN }}-V_{\text {OUT }}}{f_{\text {SW }} \times \Delta I} \times \frac{V_{\text {OUT }}}{V_{\text {IN }}}$

Increasing the value of inductance reduces the ripple current and thus, the ripple voltage. However, the larger inductance value may reduce the converter's response time to a load transient. The inductor current rating should be such that it does not saturate in overcurrent conditions. For typical ISL85410 applications, inductor values generally lie in the $10 \mu \mathrm{H}$ to $47 \mu \mathrm{H}$ range. In general, higher $\mathrm{V}_{\text {OUT }}$ causes higher inductance.

## Buck Regulator Output Capacitor Selection

An output capacitor is required to filter the inductor current. The current mode control loop allows the use of low ESR ceramic capacitors and thus supports very small circuit implementations on the PC board. Electrolytic and polymer capacitors can also be used.
While ceramic capacitors offer excellent overall performance and reliability, the actual in-circuit capacitance must be considered. Ceramic capacitors are rated using large peak-to-peak voltage swings and with no DC bias. In the DC/DC converter application, these conditions do not reflect reality. As a result, the actual capacitance may be considerably lower than the advertised value. Consult the manufacturer's datasheet to determine the actual in-application capacitance. Most manufacturers publish capacitance vs DC bias so that this effect can be easily accommodated. The effects of AC voltage are not frequently published, but an assumption of $\sim 20 \%$ further reduction generally suffices. The result of these considerations may mean an effective capacitance $50 \%$ lower than nominal and this value should be used in all design calculations. Nonetheless,
ceramic capacitors are a very good choice in many applications due to their reliability and extremely low ESR.

Use the following equations to calculate the required capacitance for ripple voltage. Additional capacitance may be used.
For the ceramic capacitors (low ESR):
$\mathrm{V}_{\text {OUTripple }}=\frac{\Delta I}{8 * \mathrm{f}_{\text {SW }} * \mathrm{C}_{\text {OUT }}}$
where $\Delta I$ is the inductor's peak-to-peak ripple current, $f_{S W}$ is the switching frequency and $\mathrm{C}_{\text {OUT }}$ is the output capacitor.

If using electrolytic capacitors,
$\mathrm{V}_{\text {OUTripple }}=\Delta I^{*} E S R$

## Loop Compensation Design

When COMP is not connected to VCC, the COMP pin is active for external loop compensation. The ISL85410 uses constant frequency peak current mode control architecture to achieve a fast loop transient response. An accurate current sensing pilot device in parallel with the upper MOSFET is used for peak current control signal and overcurrent protection. The inductor is not considered as a state variable since its peak current is constant, and the system becomes a single order system. It is much easier to design a type II compensator to stabilize the loop than to implement voltage mode control. Peak current mode control has an inherent input voltage feed-forward function to achieve good line regulation. Figure 47 shows the small signal model of the synchronous buck regulator.


FIGURE 47. SMALL SIGNAL MODEL OF SYNCHRONOUS BUCK REGULATOR


FIGURE 48. TYPE II COMPENSATOR
Figure 48 shows the type II compensator and its transfer function is expressed as shown in Equation 10:
$A_{v}(S)=\frac{\hat{v}_{C O M P}}{\hat{v}_{F B}}=\frac{G M \cdot R_{3}}{\left(C_{6}+C_{7}\right) \cdot\left(R_{2}+R_{3}\right)} \frac{\left(1+\frac{S}{\omega_{\mathrm{CZ1}}}\right)\left(1+\frac{\mathrm{S}}{\omega_{\mathrm{cz2}}}\right)}{\mathrm{S}\left(1+\frac{\mathrm{S}}{\omega_{\mathrm{cp} 1}}\right)\left(1+\frac{\mathrm{S}}{\omega_{\mathrm{cp} 2}}\right)}$
(EQ. 10)
where;
$\omega_{c z 1}=\frac{1}{R_{6} C_{6}}, \omega_{c z 2}=\frac{1}{R_{2} C_{3}}, \omega_{c p 1}=\frac{C_{6}+C_{7}}{R_{6} C_{6} C_{7}}, \omega_{c p 2}=\frac{R_{2}+R_{3}}{C_{3} R_{2} R_{3}}$

## Compensator design goal:

- High DC gain
- Choose loop bandwidth $f_{c}$ less than 100 kHz
- Gain margin: >10dB
- Phase margin: >40

The compensator design procedure is as follows:
The loop gain at crossover frequency of $f_{c}$ has a unity gain. Therefore, the compensator resistance $\mathrm{R}_{6}$ is determined by Equation 11.

$$
\begin{equation*}
R_{6}=\frac{2 \pi f_{c} V_{o} C_{o} R_{t}}{G M \cdot V_{F B}}=22.75 \times 10^{3} \cdot f_{c} V_{o} C_{o} \tag{EQ.11}
\end{equation*}
$$

where GM is the transconductance, $g_{m}$, of the voltage error amplifier in each phase. Compensator capacitor $\mathrm{C}_{6}$ is then given by Equation 12.
$C_{6}=\frac{R_{0} C_{o}}{R_{6}}=\frac{V_{0} C_{0}}{I_{0} R_{6}}, C_{7}=\max \left(\frac{R_{c} C_{0}}{R_{6}}, \frac{1}{\pi f_{S W} R_{6}}\right)$
Put one compensator pole at zero frequency to achieve high DC gain, and put another compensator pole at either ESR zero frequency or half switching frequency, whichever is lower in Equation 12. An optional zero can boost the phase margin. $\omega_{\mathrm{cz2}}$ is a zero due to $\mathrm{R}_{2}$ and $\mathrm{C}_{3}$.

Put compensator zero 2 to 5 times $f_{c}$.

$$
\begin{equation*}
\mathrm{C}_{3}=\frac{1}{\pi \mathrm{f}_{\mathrm{c}} \mathrm{R}_{2}} \tag{EQ.13}
\end{equation*}
$$

Example: $\mathrm{V}_{\mathrm{IN}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=1 \mathrm{~A}, \mathrm{f}_{\mathrm{SW}}=500 \mathrm{kHz}$, $\mathrm{R}_{2}=90.9 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{o}}=22 \mu \mathrm{~F} / 5 \mathrm{~m} \Omega, \mathrm{~L}=39 \mu \mathrm{H}, \mathrm{f}_{\mathrm{c}}=50 \mathrm{kHz}$, then compensator resistance $\mathrm{R}_{6}$ :
$\mathrm{R}_{6}=22.75 \times 10^{3} \cdot 50 \mathrm{kHz} \cdot 5 \mathrm{~V} \cdot 22 \mu \mathrm{~F}=125.12 \mathrm{k} \Omega$
It is acceptable to use $124 \mathrm{k} \Omega$ as the closest standard value for $\mathrm{R}_{6}$.

$$
\begin{equation*}
C_{6}=\frac{5 \mathrm{~V} \cdot 22 \mu \mathrm{~F}}{1 \mathrm{~A} \cdot 124 \mathrm{k} \Omega}=0.88 \mathrm{nF} \tag{EQ.15}
\end{equation*}
$$

$$
\begin{equation*}
\mathrm{C}_{7}=\max \left(\frac{5 \mathrm{~m} \Omega \cdot 22 \mu \mathrm{~F}}{124 \mathrm{k} \Omega}, \frac{1}{\pi \cdot 500 \mathrm{kHz} \cdot 124 \mathrm{k} \Omega}\right)=(0.88 \mathrm{pF}, 5.1 \mathrm{pF}) \tag{EQ.16}
\end{equation*}
$$

It is also acceptable to use the closest standard values for $\mathrm{C}_{6}$ and $\mathrm{C}_{7}$. There is approximately 3 pF parasitic capacitance from $\mathrm{V}_{\text {COMP }}$ to GND; Therefore, $\mathrm{C}_{7}$ is optional. Use $\mathrm{C}_{6}=1500 \mathrm{pF}$ and $\mathrm{C}_{7}=\mathrm{OPEN}$.
$\mathrm{C}_{3}=\frac{1}{\pi \cdot 50 \mathrm{kHz} \cdot 90.9 \mathrm{k} \Omega}=70 \mathrm{pF}$

Use $C_{3}=68 p F$. Note that $C_{3}$ may increase the loop bandwidth from previous estimated value. Figure 49, on page 19 shows the simulated voltage loop gain. It is shown that it has a 75 kHz loop bandwidth with a $61^{\circ}$ phase margin and 6 dB gain margin. It may be more desirable to achieve an increased gain margin., which can be accomplished by lowering $R_{6}$ by $20 \%$ to $30 \%$. In practice, ceramic capacitors have significant derating on voltage and temperature, depending on the type. See the ceramic capacitor datasheet for more details.


FIGURE 49. SIMULATED LOOP GAIN

## Layout Considerations

Proper layout of the power converter minimizes EMI and noise and ensures first pass success of the design. Printed Circuit Board (PCB) layouts are provided in multiple formats on the Renesas website. In addition, Figure 50 illustrates the important points in PCB layout. In reality, PCB layout of the ISL85410 is quite simple.
A multilayer PCB with GND plane is recommended. Figure 50 shows the connections of the critical components in the converter. Note that capacitors $\mathrm{C}_{I N}$ and $\mathrm{C}_{\text {OUT }}$ can each represent multiple physical capacitors. The most critical connections are to tie the PGND pin to the package GND pad and then use vias to directly connect the GND pad to the system GND plane. This connection of the GND pad to system plane ensures a low impedance path for all return current and an excellent thermal path to dissipate heat. With this connection made, place the high frequency MLCC input capacitor near the VIN pin and use vias directly at the capacitor pad to tie the capacitor to the system GND plane.
The boot capacitor is easily placed on the PCB side opposite the controller IC and two vias directly connect the capacitor to BOOT and PHASE.

Place a $1 \mu \mathrm{~F}$ MLCC near the VCC pin and directly connect its return with a via to the system GND plane.

Place the feedback divider close to the FB pin and do not route any feedback components near PHASE or BOOT. If external components are used for SS, COMP, or FS, the same advice applies.


FIGURE 50. PRINTED CIRCUIT BOARD POWER PLANES AND ISLANDS

REVISTOM MTSTOFY The revision history provided is for informational purposes only and is believed to be accurate, but not warranted.
Please visit our website to make sure you have the latest revision.

| DATE | REVISION | CHANGE |
| :---: | :---: | :---: |
| Mar 15, 2019 | FN8375.8 | Updated links throughout document. <br> Updated Related Literature section <br> Updated the Ordering Information table by adding tape and reel parts, demo board, and updated notes. <br> Under Light Load Operation section changed 300 mA to 400 mA and $\mathbf{1 \%}$ to $\mathbf{2 \%}$. <br> Added Minimum On/Off-Time Limitation section. <br> Removed About Intersil section. <br> Updated Disclaimer. <br> Updated POD L12.4x3 to the latest version changes are as follows: <br> Tiebar Note 5 updated <br> From: Tiebar shown (if present) is a non-functional feature. <br> To: Tiebar shown (if present) is a non-functional feature and may be located on any of the 4 sides (or ends). |
| Mar 13, 2015 | FN8375.7 | On page 1, updated all 36V references to 40 V and replaced Figure 2. <br> On page 6, under "Absolute Maximum Ratings" <br> for VIN to GND updated max from " +42 V " to " +43 V " <br> for PHASE to GND updated max from " 43 V " to " +44 V " <br> for EN to GND updated max from " +42 V " to " +43 V " <br> Under "Recommended Operating Conditions" updated supply voltage max from "36V" to "+40V". <br> In "Electrical Specifications" updated all occurrences of VIN value from " 36 V " to " 40 V ". <br> Replaced Figure 9, on page 8. <br> On page 14, under "Detailed Description" section updated voltage range max from " +36 V " to " +40 V ". |
| Aug 28, 2014 | FN8375.6 | POD changed from L12.3x4 back to original L12.4×3. |
| Jul 24, 2014 | FN8375.5 | Changed title of Figure 13, on page 9 from "Efficiency vs Load, PWM, $\mathrm{V}_{\text {OUT }}=5 \mathrm{~V}, \mathrm{~L}_{1}=30 \mu \mathrm{H}$ " to " $\mathrm{V}_{\text {OUT }}$ Regulation vs Load, PWM, $\mathrm{V}_{\text {OUT }}=5 \mathrm{~V}, \mathrm{~L}_{1}=30 \mu \mathrm{H}^{\prime \prime}$. <br> Replaced Figure Figure 46, on page 16. <br> Updated POD from L12.4×3 to L12.3×4 |
| Feb 25, 2014 | FN8375.4 | "Power-On Reset" on page 14 changed $10 \mu \mathrm{~A}$ to $2 \mu \mathrm{~A}$. |
| Jan 17, 2014 | FN8375.3 | "Functional Block Diagram" on page 5 changed Internal $=50 \mu \mathrm{~s}$, External $=\mathbf{2 3 0} \mu \mathrm{s}$ to Internal $=50 \mu \mathrm{~A} / \mathrm{V}$, External $=230 \mu \mathrm{~A} / \mathrm{V}$ and $600 \mathrm{~mA} / \mathrm{Amp}$ to $500 \mathrm{mV} / \mathrm{A}$ <br> "Detailed Description" on page 14 changed 0.9A to 1.5A <br> "Power-On Reset" on page 14 changed $1 \mu \mathrm{~A}$ to $10 \mu \mathrm{~A}$ <br> "PWM Control Scheme" on page 14 changed in last paragraph $50 \mu$ s vs $220 \mu \mathrm{~s}$ to $50 \mu \mathrm{~A} / \mathrm{V}$ vs $230 \mu \mathrm{~A} / \mathrm{V}$ and $600 \mathrm{~mA} / \mathrm{Amp}$ to $500 \mathrm{mV} / \mathrm{A}$ in 1st paragraph <br> "Overcurrent Protection" on page 15 changed 0.9A to 1.5A |
| Nov 22, 2013 | FN8375.2 | Initial Release. |

## Package Outline Drawing

## L12.4x3

12 LEAD DUAL FLAT NO-LEAD PLASTIC PACKAGE

## Rev 3, 3/15



TOP VIEW


TYPICAL RECOMMENDED LAND PATTERN


SIDE VIEW


DETAIL "X"

NOTES:

1. Dimensions are in millimeters. Dimensions in ( ) for Reference Only.
2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
3. Unless otherwise specified, tolerance: Decimal $\pm 0.05$
4. Dimension applies to the metallized terminal and is measured between 0.15 mm and 0.30 mm from the terminal tip.
5. Tiebar shown (if present) is a non-functional feature and may be located on any of the 4 sides (or ends).
6. The configuration of the pin \#1 identifier is optional, but must be located within the zone indicated. The pin \#1 identifier may be either a mold or mark feature.
7. Compliant to JEDEC MO-229 V4030D-4 issue E.

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